

IGBT Module

SK50MLI066

Target Data

Features

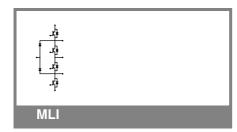
- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Trench IGBT technology
- CAL technology FWD

Typical Applications*

- 3 Level Inverter
- UPS

Remarks

- Visol = 3000V AC, 1s, 50Hz
- Dynamic measure: DUT= IGBT (Gate pin 1) and Neutral Clamp Diode (Kathode pin 16) as free-wheeling diode



Absolute Maximum Ratings $T_s = 25$ °C, unless otherwise specified						
Symbol				Values	Units	
IGBT						
V_{CES}	T _j = 25 °C T _i = 175 °C			600	V	
I _C	T _j = 175 °C	T _s = 25 °C		60	Α	
		$T_s = 70 ^{\circ}C$		50	Α	
I _{CRM}	I _{CRM} = 2 x I _{Cnom}			100	Α	
V_{GES}				± 20	V	
t _{psc}	V_{CC} = 360 V; $V_{GE} \le 20$ V; VCES < 600 V	T _j = 150 °C		6	μs	
Inverse	Diode					
I_{F}	T _j = 175 °C	T_s = 25 °C		56	Α	
		$T_s = 70 ^{\circ}C$		44	Α	
I_{FRM}	I _{FRM} = 2 x I _{Fnom}			100	Α	
I _{FSM}	t _p = 10 ms; half sine wave	T _j = 150 °C		320	Α	
Freewhe	eeling Diode					
I_{F}	T _j = 175 °C	T_s = 25 °C		56	Α	
		$T_s = 70 ^{\circ}C$		44	Α	
I _{FRM}	I _{FRM} = 2 x I _{Fnom}			60	Α	
I _{FSM}	t _p = 10 ms; half sine wave	T _j = 150 °C		320	Α	
Module	<u> </u>					
I _{t(RMS)}					Α	
T _{vj}				-40 + 175	°C	
T _{stg}				-40 +12 5	°C	
V _{isol}	AC, 1 min.			2500	V	

Characteristics $T_s =$			25 °C, unless otherwise specified				
Symbol	Conditions		min.	typ.	max.	Units	
IGBT							
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 0.8 \text{ mA}$		5	5,8	6,5	V	
I _{CES}	$V_{GE} = 0 V, V_{CE} = V_{CES}$	T _j = 25 °C			0,0026	mA	
I _{GES}	V _{CE} = 0 V, V _{GE} = 20 V	T _j = 25 °C			600	nA	
V _{CE0}		T _j = 25 °C		0,9	1,1	V	
		T _j = 150 °C		0,8	1	V	
r _{CE}	V _{GE} = 15 V	T _j = 25°C		11		mΩ	
		$T_{j} = 150^{\circ}C$		17		$m\Omega$	
V _{CE(sat)}	I _{Cnom} = 50 A, V _{GE} = 15 V			1,45		V	
		$T_j = 150^{\circ}C_{chiplev}$		1,65		V	
C _{ies}				3,1		nF	
C _{oes}	$V_{CE} = 25, V_{GE} = 0 V$	f = 1 MHz		0,2		nF	
C _{res}				0,093		nF	
t _{d(on)}				30		ns	
t _r	R_{Gon} = 16 Ω	V _{CC} = 300V		31		ns	
E _{on}	D 40.0	I _C = 50A		1,46		mJ	
t _{d(off)}	R_{Goff} = 16 Ω	T _j = 150 °C		351		ns	
t _f		V _{GE} = -7/+15 V		45		ns	
E _{off}				2,02		mJ	
$R_{th(j-s)}$	per IGBT			1,11		K/W	



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Typical Applications*

- 3 Level Inverter
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Remarks

- Visol = 3000V AC, 1s, 50Hz
- Dynamic measure: DUT= IGBT (Gate pin 1) and Neutral Clamp Diode (Kathode pin 16) as free-wheeling diode

Characteristics								
Symbol	Conditions	ĺ	min.	typ.	max.	Units		
Inverse Diode (Antiparallel Diode)								
$V_F = V_{EC}$	I_{Fnom} = 50 A; V_{GE} = 0 V	T _j = 25 °C _{chiplev} .		1,5		V		
		T _j = 150 °C _{chiplev.}		1,5		V		
V _{F0}		T _j = 25 °C		1		V		
		T _j = 150 °C		0,9		V		
r _F		T _j = 25 °C		10		mΩ		
		T _j = 150 °C		12		$m\Omega$		
I _{RRM}	I _F = 50 A	T _j = 150 °C				Α		
Q_{rr}						μC		
E _{rr}	V _R = 300V			1,07		mJ		
$R_{th(j-s)D}$	per diode			1,7		K/W		
	ling Diode (Neutral (Clampo diode)						
$V_F = V_{EC}$	I_{Fnom} = 50 A; V_{GE} = 0 V	T _j = 25 °C _{chiplev} .		1,5		V		
		T _j = 150 °C _{chiplev} .		1,5		V		
V _{F0}		T _j = 25 °C		1		V		
		T _j = 150 °C		0,9		V		
r _F		T _j = 25 °C		10		V		
		T _j = 150 °C		12		V		
I _{RRM}	I _F = 50 A	T _i = 150 °C		40		Α		
Q_{rr}	di/dt = -2670 A/μs			2,2		μC		
E _{rr}	V _R =300V			1,07		mJ		
$R_{th(j-s)FD}$	per diode			1,7		K/W		
M_s	to heat sink		2,25		2,5	Nm		
w				30		g		

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.



